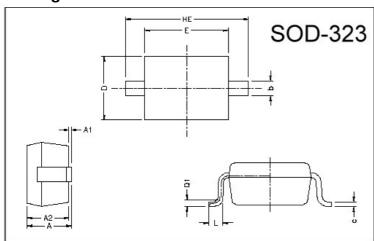
GDMBD4148

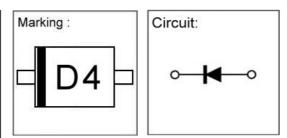
SURFACE MOUNT, SWITCHING DIODE VOLTAGE 75V, CURRENT 0.2A

Description

The GDMBD4148 is designed for high-speed switching application in hybrid thick and thin-film circuits. The devices is manufactured by the silicon epitaxial planar process and packed in plastic surface mount package.

Package Dimensions





REF.	Millimeter		REF.	Millimeter	
	Min.	Max.	111.	Min.	Max.
Α	0.85	1.05			
A1	0	0.10	L	0.20	0.40
A2	0.80	1.00	b	0.25	0.40
D	1.15	1.45	С	0.10	0.18
Е	1.60	1.80			
HE	2.30	2.70	Q1	0.15 BSC.	

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Ratings	Unit	
Junction Temperature	Tj	+150	$^{\circ}$	
Storage Temperature	Tstg	-65 ~ +150	°C	
Maximum Peak Reverse Voltage	V _{RM}	100	V	
Maximum Reverse Voltage	V_R	75	V	
Average Forward Current	I_{O}	200	mA	
Surge Current(1us)	I_{FSM}	2	Α	
Typical Junction Capacitance between Terminal (Note 1)	CJ	4.0	pF	
Maximum Reverse Recovery Time (Note2)	T _{RR}	4.0	nSec	
Total Power Dissipation	P _D	225	mW	

Electrical Characteristics at Ta = 25℃

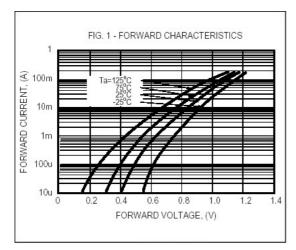
Characteristic	Symbol	Min.	Max.	Unit	Test Conditions
Forward Voltage	VF	=	1	V	IF=10mA
Reverse Breakdown	VR	100	=	V	IR=100uA
Reverse Current	IR	=	5	uA	VR=75V

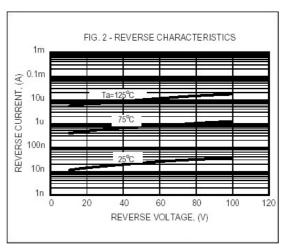
Notes: 1. Measured at 1.0 MHz and applied reverse voltage of 0 volt.

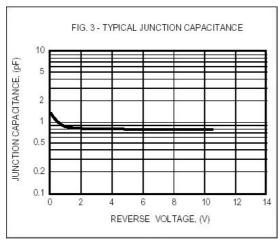
- $2. \ Measured \ at \ applied \ forward \ current \ of \ 10mA, \ reverse \ current \ of \ 1.0mA, \ Reverse \ voltage \ of \ 6.0volt \ and \ RL=100 \ ohms.$
- 3. ESD sensitive product handling required.

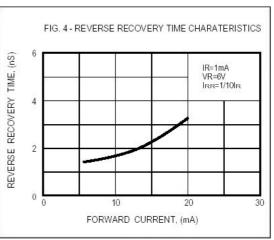
GDMBD4148 Page: 1/2

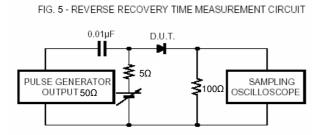
Characteristics Curve











Important Notice:

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written approval of GTM. GTM reserves the right to make changes to its products without notice. GTM semiconductor products are not warranted to be suitable for use in life-support Applications, or systems.

GTM assumes no liability for any consequence of customer product design, infringement of patents, or application assistance.

GTM assumes no liability for any consequence of customer product design, mining.

Head Office And Factory:

Taiwan: No. 17-1 Tatung Rd. Fu Kou Hsin-Chu Industrial Park, Hsin-Chu, Taiwan, R. O. C. TEL: 886-3-597-7061 FAX: 886-3-597-9220, 597-0785

China: (201203) No.255, Jang-Jiang Tsai-Lueng RD., Pu-Dung-Hsin District, Shang-Hai City, China TEL: 86-21-5895-7671 ~ 4 FAX: 86-21-38950165

GDMBD4148 Page: 2/2